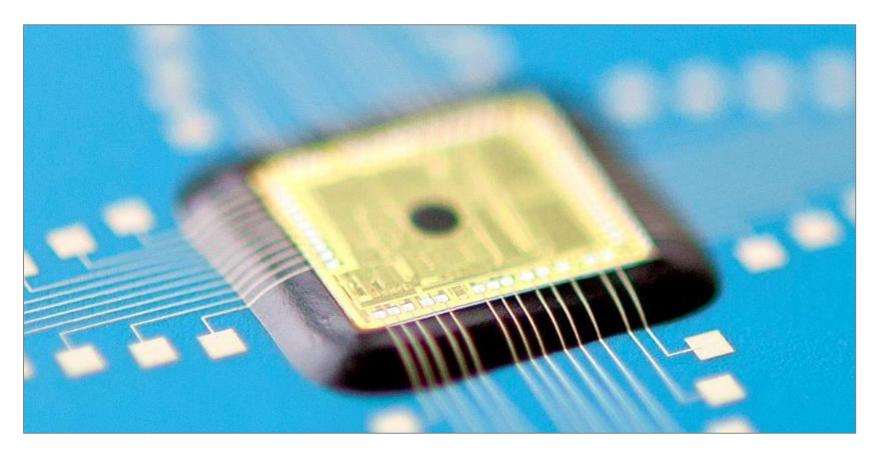
## Materials and Applications of the Ceramic Thick-Film and Multilayer Technology

Uwe Partsch, <u>uwe.partsch@ikts.fraunhofer.de</u>, phone: +49-351-2553-7696







www.ikts.fraunhofer.de

Latest update: 25.05.2016



## Outline

- Fraunhofer Gesellschaft, Fraunhofer IKTS
- Department Hybrid Microsystems @ IKTS
- Ceramic Thick-Film and Multilayer Technology
- Application Examples



## Outline

- Fraunhofer Gesellschaft, Fraunhofer IKTS
- Department Hybrid Microsystems @ IKTS
- Ceramic Thick-Film and Multilayer Technology
- Application Examples



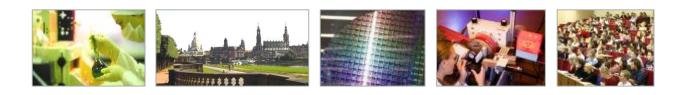
## The Fraunhofer-Gesellschaft at a Glance

#### Applied research for the immediate benefit of the economy and society





#### **Research Landscape Dresden**





- 10 Universities
  - 4 Max Planck Institutes
  - **5** Leibniz Institutes
  - **10** Fraunhofer Institutes and Units

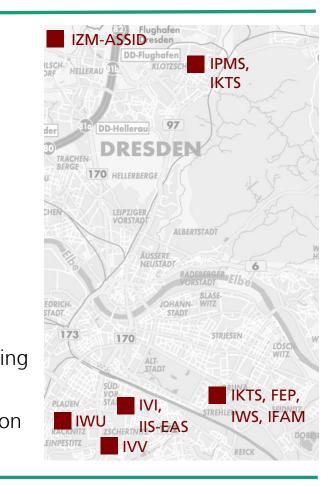
- Numerous competence centers, institutions for technology transfer and networks, e.g.:
  - BioMeT Dresden
  - DRESDEN-concept e. V.
  - Dresden Fraunhofer Cluster Nanoanalysis
  - Energy Saxony e. V.
  - Material Research Network Dresden e. V.
  - Silicon Saxony e. V.



#### Fraunhofer in Dresden

#### 10 institutes und units, biggest site of the Fraunhofer-Gesellschaft

	FEP	Institute for Organic Electronics, Electron Beam and Plasma Technology
•	IFAM	Institute for Manufacturing Technology and Advanced Materials
•	IIS-EAS	Institute for Integrated Circuits, Design Automation Division
•	IKTS	Institute for Ceramic Technologies and Systems
•	IPMS	Institute for Photonic Microsystems
	IVI	Institute for Transportation and Infrastructure Systems
	IWS	Institute for Material and Beam Technology
	IWU	Institute for Machine Tools and Forming Technology
•	IVV	Institute for Process Engineering and Packaging, Branch Lab for Processin Machinery and Packaging Technology
•	IZM-ASSID	Institute for Reliability and Microintegration, All Silicon System Integration





Active inventions 2014:6618Patent applications 2014:563



2013: Fraunhofer in

- → 14<sup>th</sup> place of the most active patent applicants and
- 6<sup>th</sup> place of the most active trademark applicants at the German Patent and Trademark Office



2014: Fraunhofer is counted among the 100 largest applicants at the European Patent Office (place 56).



2014: According to a study by the international media concern Thomson Reuters, Fraunhofer is counted among the **»Top 100 Global Innovators«.** (the other 3 German companies in the TOP 100 are BASF, BOSCH, Siemens)



#### **Fraunhofer IKTS in Figures**

Branches and Sites of Fraunhofer IKTS



#### Headquarter

Dresden,
Winterbergstraße



- Branches
- Hermsdorf, Thuringia



Dresden-Klotzsche

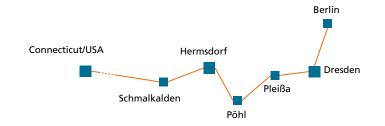
#### Sites

- Application Center Battery Technology Pleißa, Saxony
- Application Center Bioenergy Pöhl, Saxony
- Application Center Membrane Technology Schmalkalden, Thuringia













#### Fraunhofer Center

 for Energy Innovation CEI, Connecticut/USA

© Fraunhofer

#### Fraunhofer IKTS in Figures

Branches and Sites of Fraunhofer IKTS

|--|

Branches and sites	Head- quarter	Hermsdorf branch	Dresden- Klotzsche branch	Total
Personnel (full-time equivalents)	310	145	125	580
Operating budget in million €	26.3	10.8	13	50.1
Industrial revenues in million €	9.2	5.1	4.3	18.6
Latest update: April 2015				

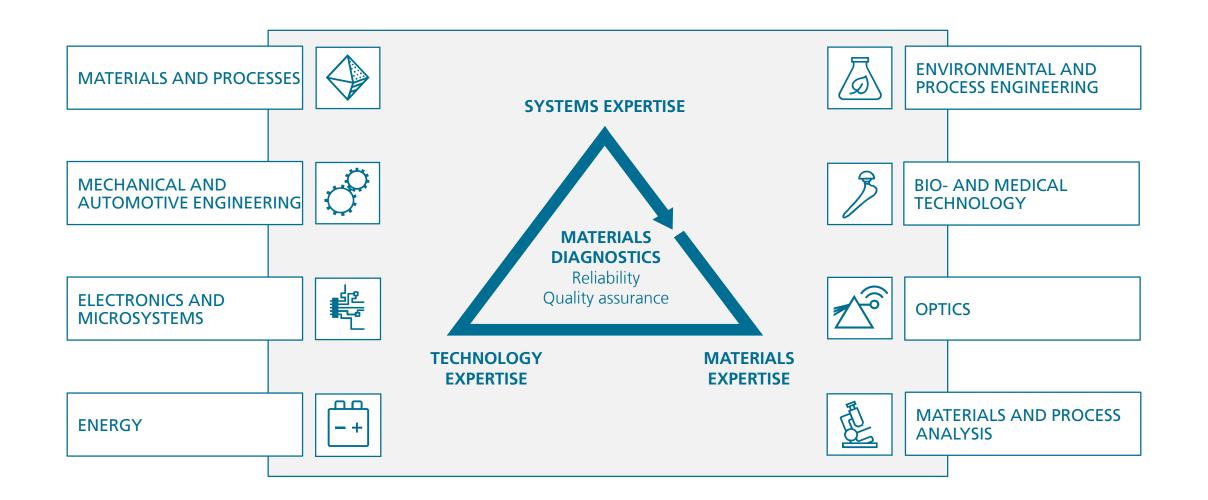
Institute Director:

Prof. Dr. Alexander Michaelis



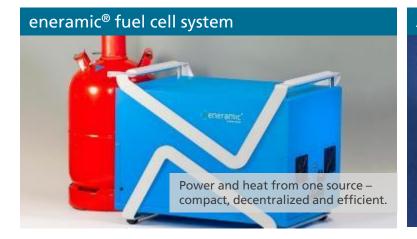


#### **IKTS Business Divisions**





#### **Current Research Projects**

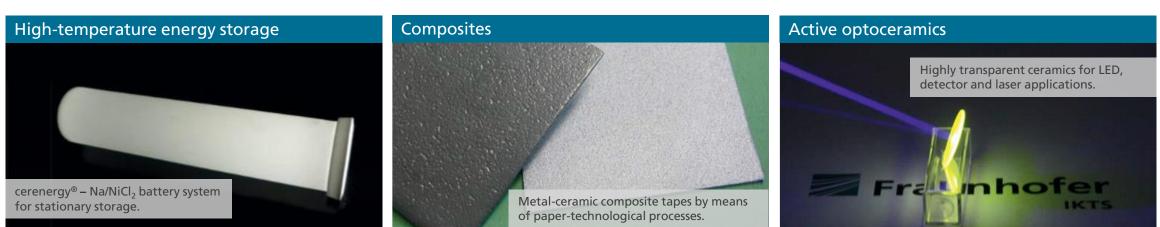


#### Additive manufacturing



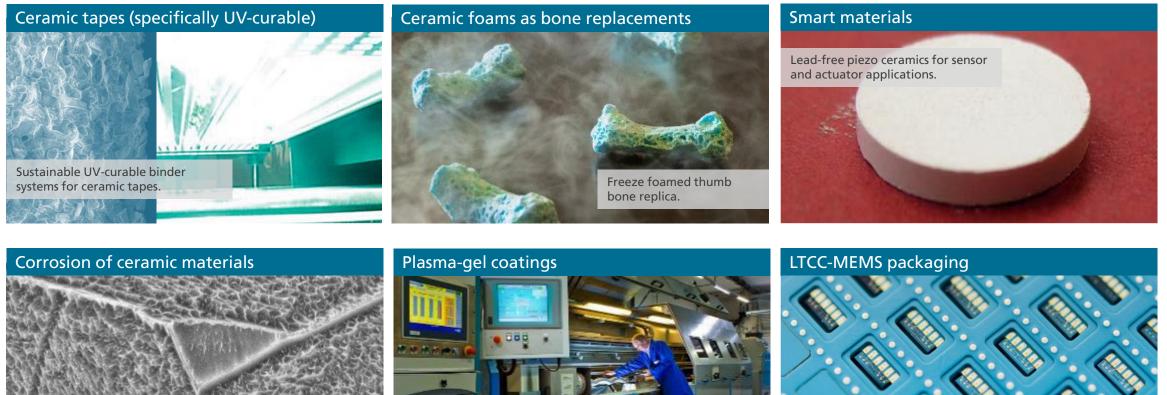
#### Superhard wear-resistant materials







#### **Current Research Projects**



Examination of electrochemical corrosion mechanisms of ceramics.



Manufacturing of reliable and robust sensors and actuators.



## Outline

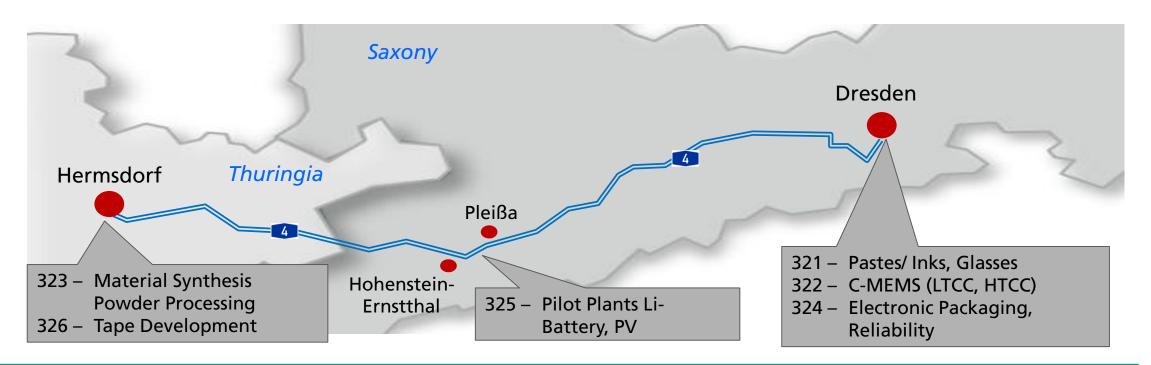
- Fraunhofer Gesellschaft, Fraunhofer IKTS
- Department Hybrid Microsystems @ IKTS
- Ceramic Thick-Film and Multilayer Technology
- Application Examples



#### **Department Hybrid Microsystems**

Figures

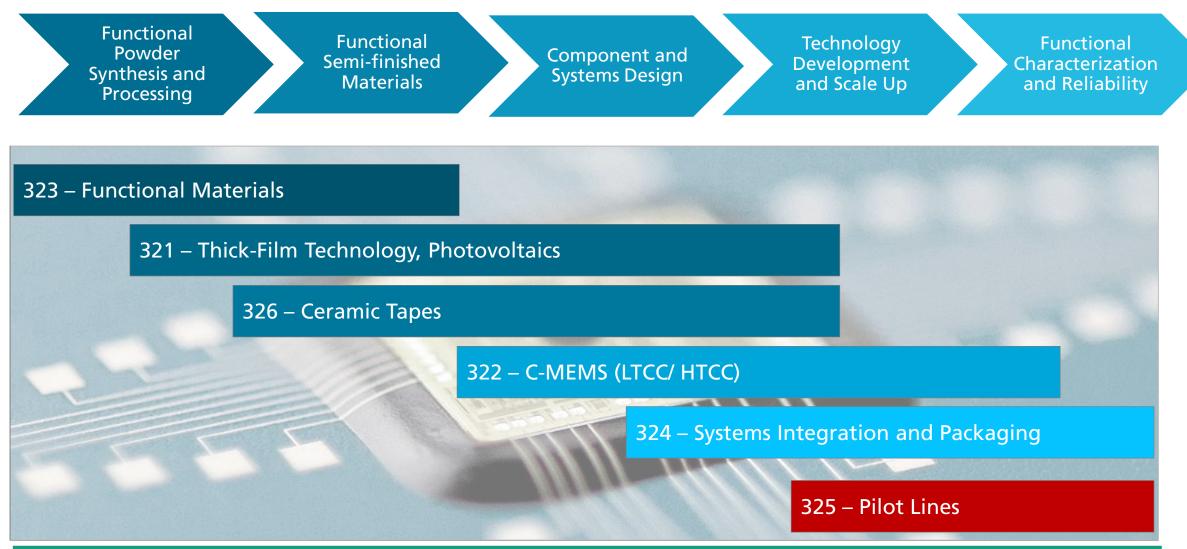
- 3 sites, 6 working groups
- 48 employees
- Budget 2015 approx. 5.9 Mio. €
- Focused topics: Ceramic thick-film and multilayer technology





#### **Department Hybrid Microsystems**

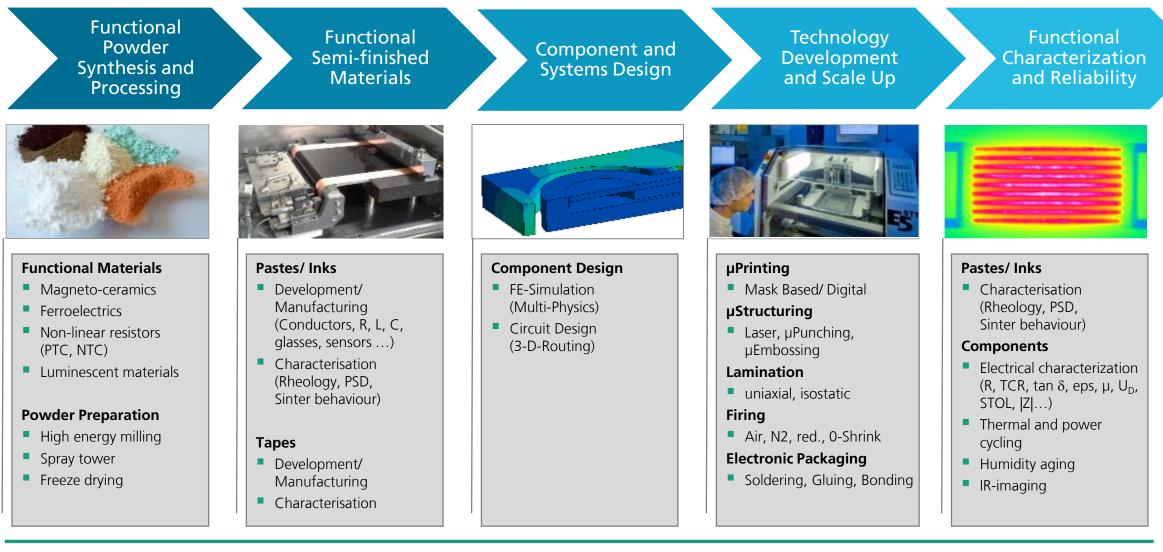
Value Chain





#### **Department Hybrid Microsystems**

Value Chain



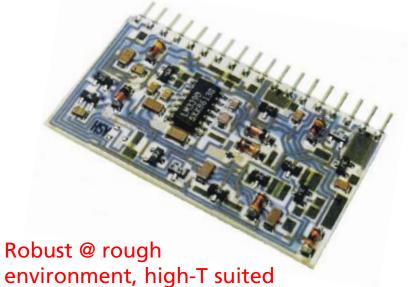


## Outline

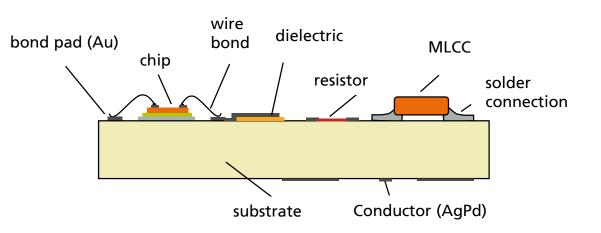
- Fraunhofer Gesellschaft, Fraunhofer IKTS
- Department Hybrid Microsystems @ IKTS
- Ceramic Thick-Film and Multilayer Technology
- Application Examples



Thick-film based hybrid circuits Electronic modules consisting of different components, materials and manufacturing technologies, integrated on a sintered ceramic substrate

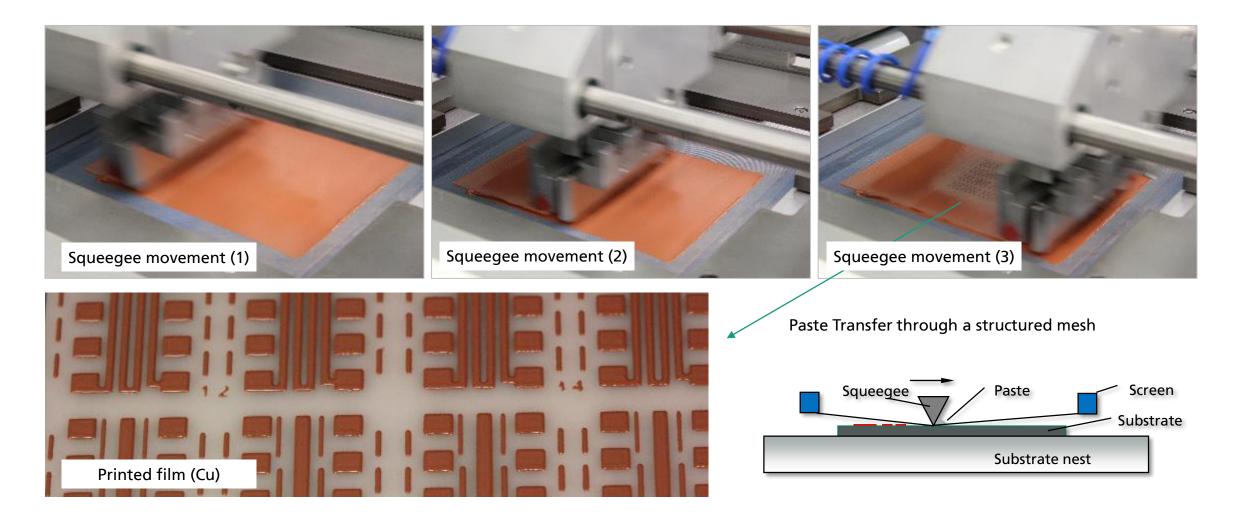


- High thermal losses
- High thermal losses
- Perfect electrical isolation, RF-suited
- Reliable (thermo-mechanical matching to Si)





Film Deposition - Screen /Stencil Printing





Film Deposition - Screen /Stencil Printing

- Functional pastes/ films
  - Conductor lines (Ag, AgPd, Cu, Ni, Au, Pt, W)
  - Passives (R, L, C)
  - Glasses
  - Sensors, actuators, ion conductors ...
- Structural sizes
  - thickness = 2.. 100 µm/ width = 0.1 .. 5 mm
- process
  - printing, drying, firing



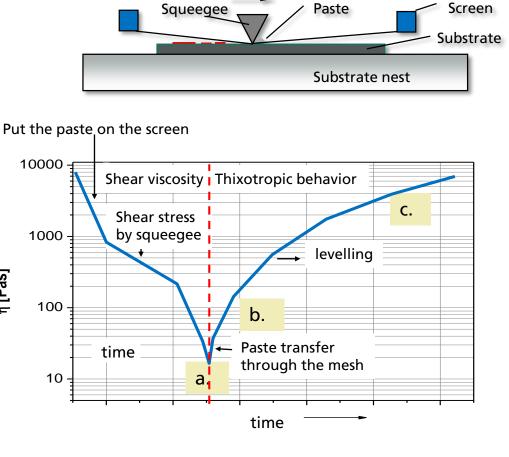


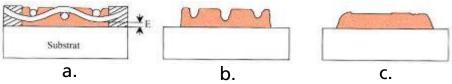


η [Pas]

Screen-emulsion, -mesh © Koenen

Stencil mask © Fraunhofer IKTS







Film Deposition - Screen /Stencil Printing

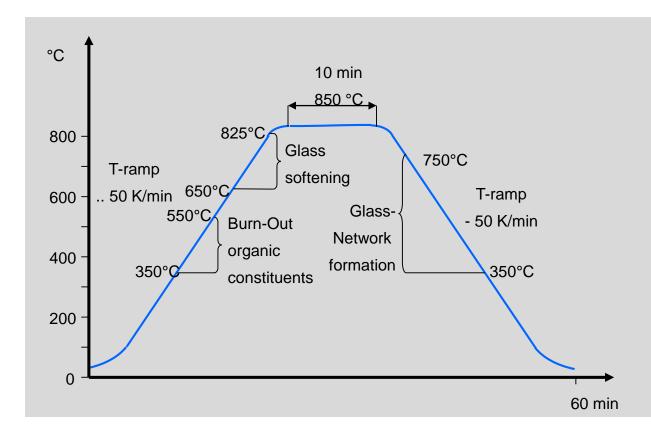
Metallization pastes

Paste material	Resistance [mΩ/• ]	Adhesion [kg/mm²]	Soldering	Bonding	Costs	Remarks
Ag	1 – 10	0,7 – 0,9	✓		+	Ag-migration
AgPd	10 – 30	0,9 – 1,1	$\checkmark$	±	±	Standard paste
AgPt	3 – 20	0,9 – 1,1	✓	+	-	Migration stable
Au	1 – 6	0,9 – 1,1		++	-	Bond pads, MIL
AuPd	20 – 100	0,6 - 0,8	✓	++	-	MIL
AuPt	20 – 100	0,7 – 0,9	$\checkmark$	+		Solder able
Cu	1 – 4	0,5 - 0,7	$\checkmark$	±	++	Cost effective



Film Sintering – Belt Oven

Typical thick-film thermal processing





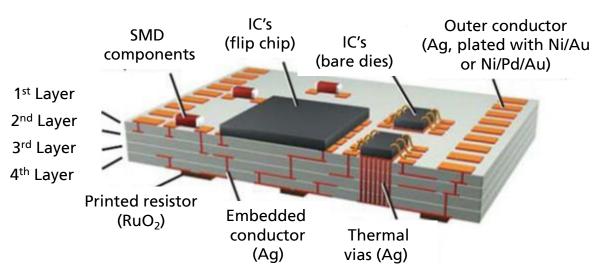
Belt-oven Centrotherm DO 4800 for thick-film applications Source: Fraunhofer IKTS



Ceramic multilayer

Succession of (different) ceramic layers which are differently structured, printed with functional layers and subsequently pressed (laminated) and are sintered.

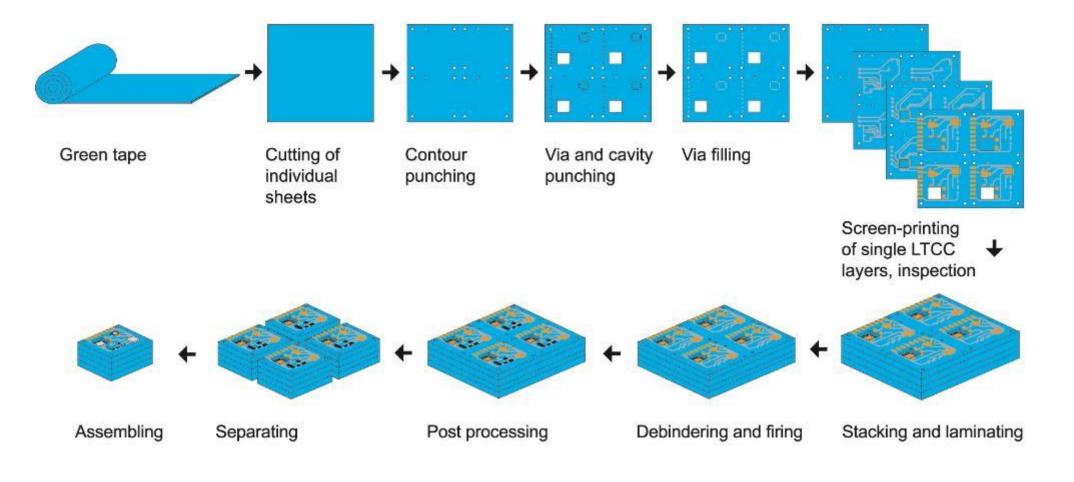
- Technology features
  - Co-firing!
  - 20 and more layers (> 1000 @ MLCC)
  - Layer thickness 5.. 300 μm
  - Lateral dimensions up to 8" x 8" (multiple printed boards)
- Applications (high density interconnects)
  - Rough environment
  - RF
  - High reliability



Source: Murata



Process flow





Materials for Ceramic 3D-Substrates

Property	Al <sub>2</sub> O <sub>3</sub>	HP Si <sub>3</sub> N <sub>4</sub>	AIN	LTCC	ССМ	PI	FR4
		Ceramics/ Gl	ass-ceramics	Steel	Polymers		
Sintering temperature [°C]	> 1500	> 1500	> 1400	< 900	1000	260	120
CTE [10 <sup>-7</sup> /K ]	75	31	34	50 - 70	125	270	300
Thermal Conductivity [W/mK]	20	50	150	4 - 6	25	1,2	0,2
Dielectric constant	9,5	5	10,0	3 - 5	5-6	3,5	5,0
Loss tangent (x 10 <sup>-3</sup> ) @10 MHz	0,3	4,5	2,0	0,1	2,0	3,0	5,0
Cost factor approx.	1	< 40	< 40	10	4	0,5	0,25



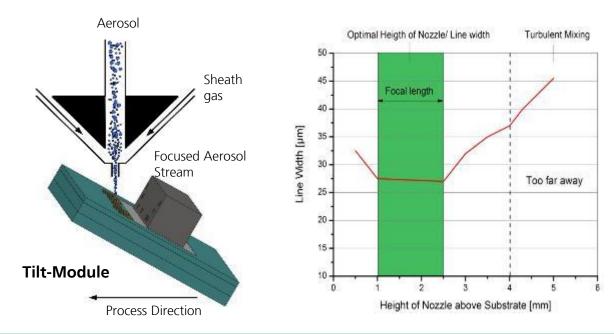
Film Deposition Technologies

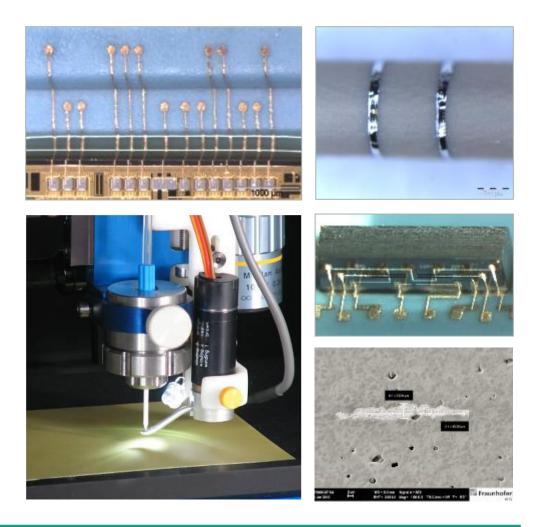
	Screen-/ stencil printing	Tampon printing	Micro-extrusion/ dispensing	Ink-jet- printing	Aerosol-jet- printing	
Туре	Mask	-based	digital			
Viscosity [mPa*s]	10.000	10.000	10.000	10	101000	
Particle size [µm]	0,1 - 5	0,1 - 5	0,1 - 5	0,01 - 0,1	0,01 - 1	
Clock rate [s]	1,5	3	Structure depended	Structure depended	Structure depended	
Printing resolution [µm]	30 - 50	80	50	40	10	
3D-Option	tubular	restricted	restricted	no	yes	



Aerosol-Jet Printing

- Fully digital, no masks
- Extremely high printing resolution (10 μm)
- 3D-capability
- Nano-Inks (e.g. silver) with low sintering temperatures (polymer substrates)







Decal-Transfer Technology

- Process
  - Pre-print of the functional layers on siliconized paper
    - Silver
    - Encapsulation
    - Transfer layer
  - Transfer to the substrate (2D, 3D)
  - Co-firing
- Bulk resistance, good adhesion, high isolation resistance







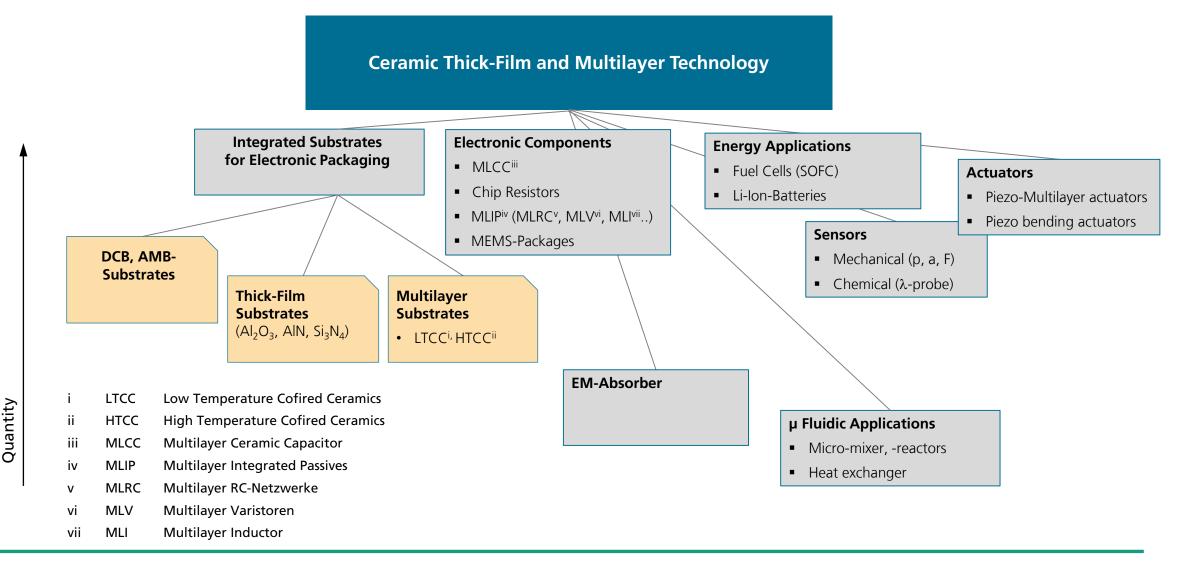




## Outline

- Fraunhofer Gesellschaft, Fraunhofer IKTS
- Department Hybrid Microsystems @ IKTS
- Ceramic thick-film and multilayer technology
- Application Examples







#### Automotive Applications

#### **Around engine**: <150°C (170)

- propulsion system
- electronic break assistant

Engine, gear control:

**Passenger cell**: 85°C (up to 105°C)

- navigation system
- comfort functions
- cruise control
- safety systems

#### Components near

**wheel**: <300°C

- brake by wire
- steer by wire

Source: DaimlerChrysler AG, Project: HotEl www.mikrotechnische-produktion.de

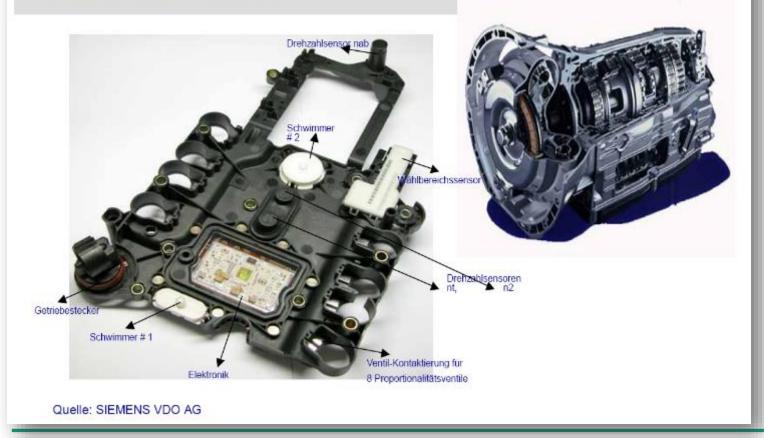
- Ceramic Substrates/ Components
  - High/ low temperature
    - Engine  $\rightarrow$  300°C
    - Near wheel  $\rightarrow$  300°C
    - Exhaust  $\rightarrow$  600°C
  - Thermal shock, cycles
  - Mechanical shock, vibration
  - Voltage spikes
  - Electrostatic discharge
  - Salt spray, humidity, break fluid, transmission fluid, engine coolant,oil



<300°C

Automotive Applications - LTCC-based Gear Control

Applikationsbeispiel Automobilelektronik Getriebesteuerung in LTCC Technik (SIEMENS - VDO) für Mercedes Benz 7G-Tronic



**ZVEI:** 



Automotive Applications - LTCC-based Gear Control

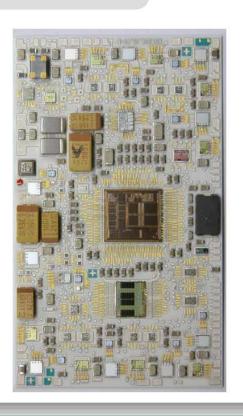
Applikationsbeispiel Automobilelektronik ECU in LTCC Technologie für Mercedes Benz 7G- Tronic

#### ECU für die Getriebesteuerung enthält

>32-BIT uC-Core Motorola MPC555, 448 kByte internes Flash, 26 Kbyte internes RAM

- ≻1 Mbyte externes Flash
- ≻4 kByte EEPROM
- >3,3V- und 5V-Spannungsversorgung
- Endstufen zur Ansteuerung von Proportionalventilen
- >Integrierter Temperatursensor
- CAN Interface
- >Frequenzeingänge/Analogeingänge
- >EMV optimiertes Design

Quelle: SIEMENS VDO AG

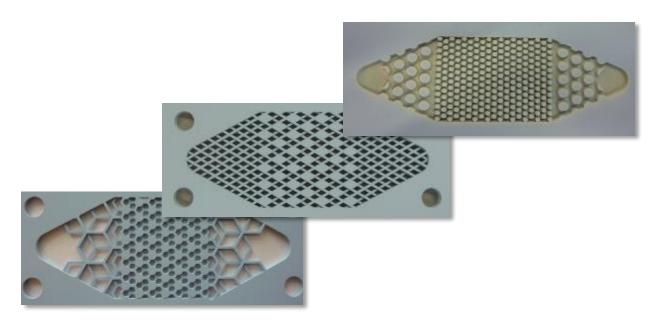


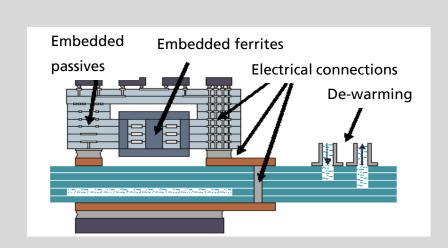
ZVEI:



Power Electronics - Ceramic Multilayer DCB-Substrates

- "Ceramic packages for robust signal- and power electronics" -KAIROS
  - Funded by: BMBF (VDI/VDE-IT), 07/2011 07/2014
  - Project partner: Continental, Siemens AG, Curamik, Via Electronic, Friedrich-Alexander-University Erlangen-Nürnberg (LEB)





- Frequency converter 10 kW
- Integration of logic and power functionality on one DCB substrate
- DCB integrated cooling using HTCCtechnology



Power Electronics - Thick-Cu Metallization

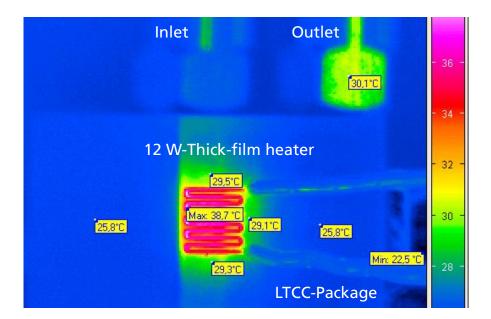
- Thick-film Ag, AgPd, Cu on  $Al_2O_3$ , AlN,  $Si_3N_4$
- Alternative to DCB/ AMB
  - High printing resolution (< 100 μm)</p>
  - Thickness from 15 up to 300 μm (combination of logic and power on one substrate)
  - "Smooth" topography, gradient layers prevent mechanical strain peaks

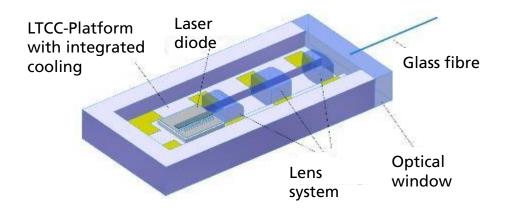




Microsystems – Laser-optical LTCC-Package

- 20 W Laser Emitter (8 W optical) → Simulation with thick-film heater (12 W) on AIN with active cooling (water)
- T max (heater spreader 29,5 °C), without active cooling 270 °C
  → R<sub>th</sub>=0,31 K/W (@ 0,3 bar cooling pressure)







LTCC package with open cooling channels

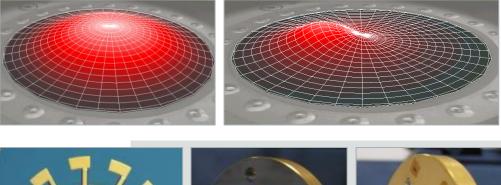


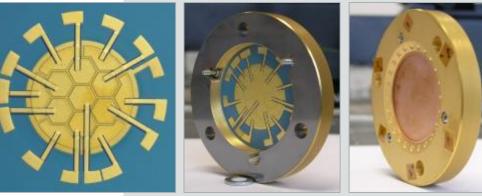
LTCC-package with mounted AINsubstrate and liquid connectors



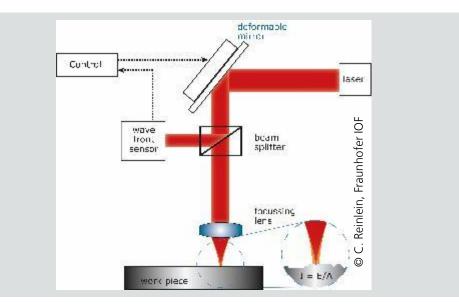
Microsystems - LTCC-based deformable Mirror

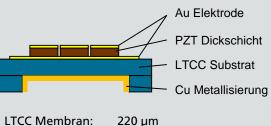
- Deform-able mirror for beam shaping in Laser technology
- 6 PZT-Oktagones for the compensation of thermal effects (Correction of wave front)





Backside: PZT Thick-Film on LTCC, Frontside: Cu (plated)





IOF

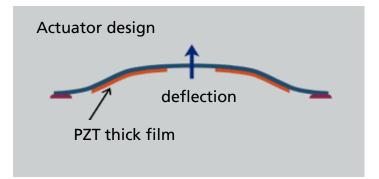
34.7 mm Durchmesser: 100 µm PZT Dicke: Cu-Schicht: 150 µm

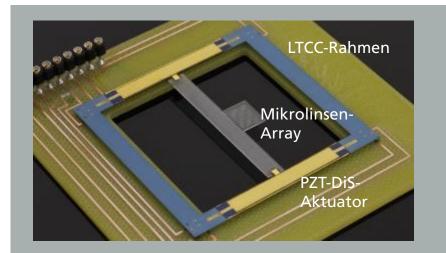


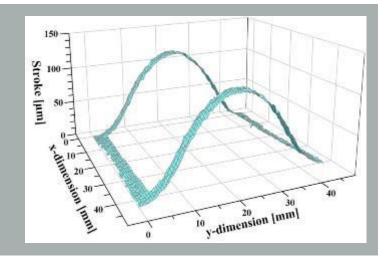


Microsystems - LTCC-based Micro-Positioning Stage

- Experimental Set-up
  - LTCC 45 x 45 x 0.17 mm<sup>3</sup> with internal wiring
  - Piezo-electric (PZT) Actuator 25 x 4.2 x 0.1 mm<sup>3</sup>
  - Micro lens-Array 5.7 x 4.3 mm<sup>2</sup>
- **Experimental results** 
  - Deflection  $\Delta z = 115 \ \mu m @ E = 2 \ kV/mm$ , linear behavior
  - Blocking force  $F_B = 110 \text{ mN} @ E = 2 \text{ kV/mm}$







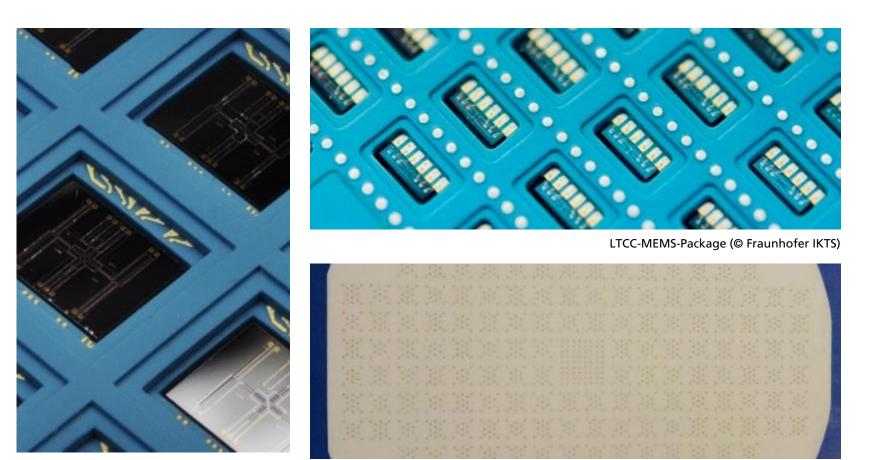


IOF



Microsystems - LTCC-based MEMS Packages

- LTCC = 3D-Package for
  - MEMS
  - MOEMS
  - LED
  - Electronic components
- requirements (HT-stable)
  - Mechanical positioning
  - Electrical contacts
  - De-warming
- Packaging Technologies
  - Soldering, bonding, gluing
  - Anodic bonding

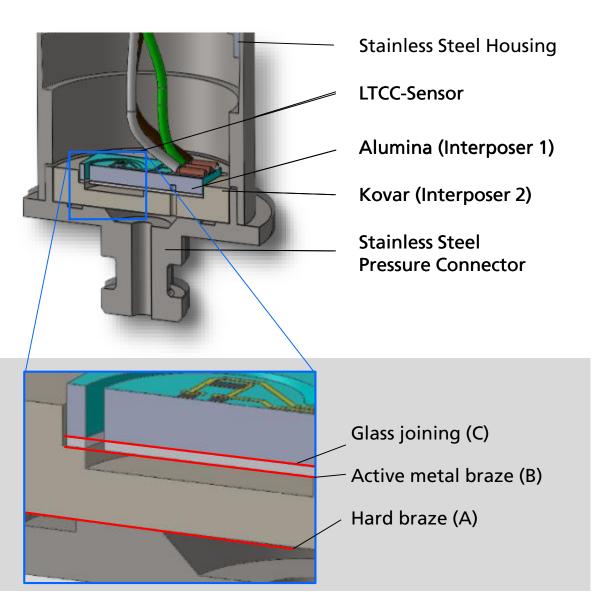


LTCC-Substrate for MEMS-Package (Wafer Level) (© Fraunhofer IKTS)



Sensors - LTCC-Pressure Sensor for T=300°C

- Structural materials
  - LTCC DP 951 (Sensor)
  - Alumina (96 % Rubalit<sup>®</sup> 708 S Interposer 1)
  - Kovar<sup>®</sup> (1.3981, Fe-29Ni-17Co Interposer 2)
  - Stainless steel (1.4542, X5CrNiCuNb16-4 pressure connector, housing)
- Joining materials
  - Ni-hard braze (Joining step A; steel/Kovar)
  - AgCu-active metal braze (Joining step B; Kovar/alumina)
  - Glass joining (Joining step C; alumina/LTCC)



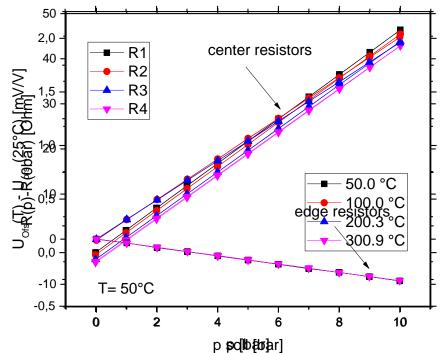
\* J. Schilm, A. Goldberg, U. Partsch, W. Dürfeld, D. Arndt, A. Pönicke and A. Michaelis, J. Sens. Sens. Syst., 5, 1–11, 2016



Sensors - LTCC-Pressure Sensor for T=300°C

- Measurements (according DIN ISO 18086)
  - Characteristic curves (U<sub>ofs</sub>, S, FS, L, H)
  - Temperature dependence (U<sub>ofs</sub>, S, FS, L, H) = f(T)
  - Measurement of the single resistors
  - Thermal cycling  $\Delta(U_{ofs}, S, FS, L, H) = f(T)$
- Proper sensor functionality up to 300°C
- Small temperature dependencies of
  - U<sub>ofs</sub>
  - S
- Full T-range: extremely low L (0.1%FS)
- H
  - Up to 200°C < 0.25%FS
  - Up to 300°C < 0.45%FS







# Thank you for your attention!

Further information:

uwe.partsch@ikts.fraunhofer.de

